

TP6L60M TP6L60M(H) **120-cell**

360 - 380W

9BB Half-cut Mono Perc

SYSTEM & PRODUCT CERTIFICATES



- ISO 9001: 2015 Quality Management System
- ISO 14001: 2015 Environment Management System
- ISO 45001: 2018 Occupational Health and Safety Management Systems







KEY FEATURES

9BB Half-cut Cell Technology

New circuit design, lower internal current, lower Rs loss Ga dopped wafer, attenuation < 2% [1st year] / 0.55% [Linear]



Significantly Lower the Risk of Hot Spot

Special circuit design with much lower hot spot temperature



Excellent Anti-PID Performance

2 times of industry standard Anti-PID test

PERFORMANCE WAR



ELECTRICAL CHARACTERISTICS

Testing Condition	STC	NMOT	STC	NMOT	STC	NMOT	STC	NMOT	STC	NMOT
Maximum Power (Pmax/W)		 		 				 		
Operating Voltage (Vmpp/V)		! ! !		 				 		
Operating Current (Impp/A)		 		 				 	1	
Open-Circuit Voltage (Voc/V)		 		 				 		
Short-Circuit Current (Isc/A)		 		 				 		
Module Efficiency (%)	19.	70	20.	.00	20.	30	20	.60	20.	90

STC: Irradiance 1000W/m², Spectra at AM1.5, Module Temperature 25 $^{\circ}$ C. Power output tolerance: 0~+5W, Test uncertainty for Pmax: $\pm 3\%$ NMOT: Irradiance 800W/m², Spectra at AM1.5, Ambient Temperature 20 $^{\circ}$ C, Wind speed 1m/s

MECHANICAL CHARACTERISTICS

Cell Type	Monocrystalline Silicon (9Busbar)				
No. of Cells	120pcs in series (6*20)				
Module Dimensions	1755*1038*30mm (69.09*40.87*1.18 inches)				
Weight	19.5kg (42.99lbs)				
Front Glass					
Frame	Anodized Aluminium Alloy				
Junction Box	IP68, 3 Bypass Diodes				
Output Cables	4mm²(IEC),12AWG(UL) 300mm in Length or Customized Length				
Connectors	T01/LJQ-3-CSY/MC4/MC4-EV02				

I-V CURVE

TECHNICAL DRAWINGS

TEMPERATURE CHARACTERISTICS

Temperature Coefficient of Pmax	
Temperature Coefficient of Voc	
Temperature Coefficient of Isc	
Nominal Module Operating Temperature(NMOT)	

PACKING CONFIGUP

